

Quad Line 12V ESD Protection Diode Array UESD16V8S4C SOT23-6

General Description

The UESD16V8S4C of TVS diode array is designed to protect sensitive electronics from damage or latch-up due to ESD, for high voltage applications where board space is at a premium. It is unidirectional device and may be used on lines where the signal polarities are above ground, each device will protect up to four lines.

TVS diodes are solid-state devices feature large cross-sectional area junctions for conducting high transient currents, specifically for transient suppression. It offers desirable characteristics for board level protection including fast response time, low operating, low clamping voltage, and no device degradation.

The UESD16V8S4C may be used to meet the immunity requirements of IEC 61000-4-2, level 4. The small package makes them ideal for use in portable electronics such as cell phones, PDA's, notebook computers, and digital cameras.

Applications

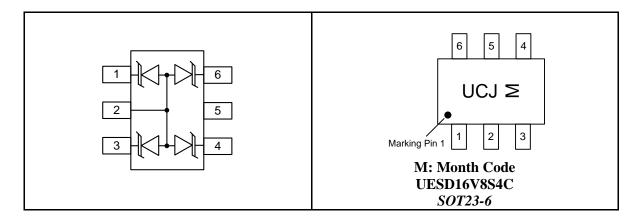
- Cellular Handsets & Accessories
- Telecom Equipment
- Notebooks & Handhelds
- Portable Instrumentation
- Industrial PC
- **Industrial Automation**

Features

- Transient Protection for Data & Power Lines to IEC 61000-4-2 (ESD) ±15kV (Air), ±8kV (Contact)
- Protect Four I/O Lines
- Ultra-Small SOT23-6 Package
- Working Voltage: 12V
- Low Leakage Current
- Low Operating and Clamping Voltage
- Solid-State Silicon Avalanche Technology

Pin Configurations

Top View



Ordering Information

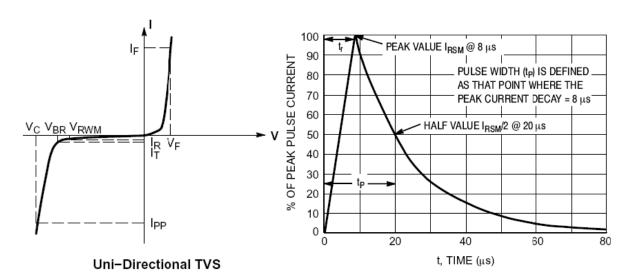
| Part Number | Working Voltage | Packaging Type | Channel | Marking Code | Shipping Qty |
|-------------|--------------------|-------------------|---------|-----------------|-------------------------------|
| UESD16V8S4C | 12.0V | SOT23-6 | 4 | UCJ | 3000pcs/7 Inch Tape & Reel |

Absolute Maximum Ratings

| Rating | Symbol | Value | Unit |
|---|-------------|---------------|----------------|
| Peak Pulse Power (t _P =8/20μs) | P_{PK} | 140 | Watts |
| Maximum Peak Pulse Current (t _P =8/20μs) | I_{PP} | 5.9 | Amps |
| Lead Soldering Temperature | $T_{\rm L}$ | 260 (10 sec.) | $\mathcal C$ |
| Operating Temperature | T_{J} | -55 to +125 | $\mathcal C$ |
| Storage Temperature | T_{STG} | -55 to +150 | ${\mathcal C}$ |

Symbol Definition

| Parameter | Symbol |
|--|------------------|
| Maximum Reverse Peak Pulse Current | I_{PP} |
| Clamping Voltage @ I _{pp} | $V_{\rm C}$ |
| Working Peak Reverse Voltage | $V_{ m RWM}$ |
| Maximum Reverse Leakage Current @ V _{RWM} | I_R |
| Breakdown Voltage @ I _T | $V_{ m BR}$ |
| Test Current | I_{T} |
| Forward Current | I_{F} |
| Forward Voltage @ I _F | $ m V_{F}$ |
| Peak Power Dissipation | P_{PK} |
| Max. Capacitance @ V _R =0V, f=1MHz | С |



Electrical Characteristics (T=25 $^{\circ}$ C, Device for 12.0V Reverse Stand-Off Voltage)

| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|------------------------------|------------------|--------------------------------------|-----|-----|-----|------|
| Reverse Stand-Off Voltage | $V_{\rm RWM}$ | | | | 12 | V |
| Reverse Breakdown Voltage | V_{BR} | I _T =1mA | 16 | | 18 | V |
| Reverse Leakage Current | I_R | $V_{RWM}=12V, T=25 ^{\circ}\text{C}$ | | | 0.5 | μΑ |
| Clamping Voltage | $V_{\rm C}$ | $I_{PP}=5.9A, t_p=8/20\mu s$ | | | 23 | V |
| Junction Capacitance | C_{J} | $V_R=0V$, $f=1MHz$ | | 20 | 30 | pF |

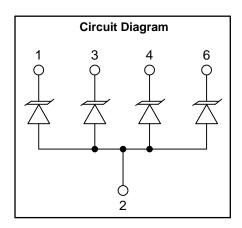
Applications Information

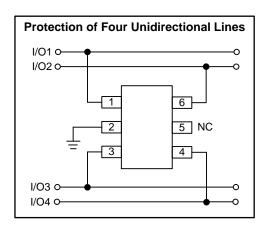
UESD16V8S4C ESD protection diode is designed to protect quad data, I/O, or power supply line. The device is unidirectional and may be used on lines where the signal polarity is above ground. The cathode should be placed towards the line that is to be protected.

Device Connection for Protection of Quad Data Lines

The Quad TVS Diode Array is designed to protect up to four unidirectional data lines. The device is connected as follows:

Unidirectional protection of four I/O lines is achieved by connecting pins 1, 3, 4 and 6 to the data lines. Pin 2 is connected to ground. The ground connection should be made directly to the ground plane for best results. The path length is kept as short as possible to reduce the effects of parasitic inductance in the board traces.





Circuit Board Layout Recommendations for Suppression of ESD

Good circuit board layout is critical for the suppression of ESD induced transients. The following guidelines are recommended:

Place the TVS near the input terminals or connectors to restrict transient coupling.

Minimize the path length between the TVS and the protected line.

Minimize all conductive loops including power and ground loops.

The ESD transient return path to ground should be kept as short as possible.

Never run critical signals near board edges.



Use ground planes whenever possible. For multilayer printed-circuit boards, use ground vias. Keep parallel signal paths to a minimum.

Avoid running protection conductors in parallel with unprotected conductor.

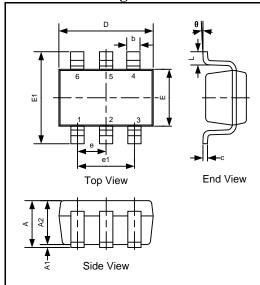
Minimize all printed-circuit board conductive loops including power and ground loops.

Avoid using shared transient return paths to a common ground point.

Package Information

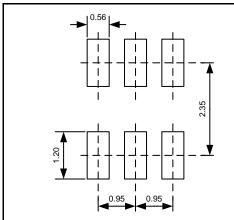
UESD16V8S4C SOT23-6

Outline Drawing



| DIMENSIONS | | | | | | | |
|------------|-------------|------|------|----------|-------|-------|--|
| Symbol | MILLIMETERS | | | INCHES | | | |
| | Min | Тур | Max | Min | Тур | Max | |
| A | 1.013 | 1.15 | 1.40 | 0.040 | 0.045 | 0.055 | |
| A1 | 0.00 | 0.05 | 0.10 | 0.000 | 0.002 | 0.004 | |
| A2 | 1.00 | 1.10 | 1.30 | 0.039 | 0.043 | 0.051 | |
| b | 0.30 | - | 0.50 | 0.012 | - | 0.020 | |
| С | 0.10 | 0.15 | 0.20 | 0.004 | 0.006 | 0.008 | |
| D | 2.82 | - | 3.10 | 0.111 | - | 0.122 | |
| Е | 1.50 | 1.60 | 1.70 | 0.059 | 0.063 | 0.067 | |
| E1 | 2.60 | 2.80 | 3.00 | 0.102 | 0.110 | 0.118 | |
| e | 0.95REF | | | 0.037REF | | | |
| e1 | 1.90REF | | | 0.075REF | | | |
| L | 0.30 | - | 0.60 | 0.012 | - | 0.024 | |
| θ | 0 ° | - | 8° | 0 ° | - | 8° | |

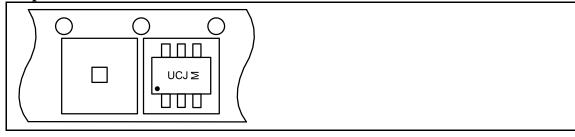
Land Pattern



NOTES:

- 1. Compound dimension: 2.92×1.60;
- 2. Unit: mm;
- 3. General tolerance ±0.05mm unless otherwise specified;
- 4. The layout is just for reference.

Tape and Reel Orientation



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